

TOSHIBA Photocoupler GaAs Ired & Photo-Triac

TLP3530

Triac Driver Programmable Controllers AC-Output Module Solid State Relay

The TOSHIBA TLP3530 consists of a photo-triac optically coupled to a gallium arsenide infrared emitting diode in a 16 lead plastic DIP package for 2 channels output..

- Peak off-state voltage: 400V(min.)
- Trigger LED current: 10mA(max.)
- On-state current: 1.0A_{rms}(max per 1ch) 1.4Arms(max per 2ch)
- Isolation voltage: 2500Vrms (min.)

Trigger LED Current

Classi- *	Trigger LED Current (mA)		Marking Of
fication	V _T =6V, Ta=25°C		Classification
	Min	Max	
(IFT7)	_	7.0	T7
Blank	—	10	T7, blank

* : (IFT7): TLP3530(IFT7)

(Note): Application type name for certification test, please use standard product type name, i.e. TLP3530(IFT7): TLP3530





Anode

N.C

Cathode

Triac T1

Triac gate*

Triac T2 (common)

3,6 :

2.7

4,5

12,13

10,15 :

9,16 :

Pin Configuration(top view)



Maximum Ratings (Ta = 25°C)

Characteristic			Symbol	Rating	Unit		
	Forward current	١ _F	50	mA			
LED	Forward current derating (Ta ≥	ΔI _F / °C	-0.7	mA / °C			
	Peak forward current (100µs p	I _{FP}	1	А			
	Reverse voltage		V _R	5	V		
	Junction temperature	Tj	125	°C			
	Off-state output terminal volta	V _{DRM}	400	V			
	On-state RMS Current	Ta=40°C	IT(RMS)	1.0(per 1 ch)			
		1a-40 C		1.4(per 2 ch)	A		
		Ta=60°C		0.7(per 1 ch)			
ū				1.0(per 2ch)			
Detector	On-state current derating(Ta 2	O_{2} state current densities (Ta > 40° C)			mA / °C		
ă		ΔI _T / °C	-20.0(per 2 ch)				
	Peak current from snubber cire	I _{SP}	2	А			
	(100µs pulse, 120pps)		2	A			
	Peak nonrepetitive surge curre	ITSM	10	А			
	Junction temperature	Тј	110	°C			
Storage temperature range			T _{stg}	-40~125	°C		
Operating temperature range			T _{opr}	-20~80	°C		
Lead soldering temperature (10s)			T _{sol}	260	°C		
Isolatio	on voltage (AC, 1min., R.H.≤ 60º	BVS	BV _S 2500				

(Note): Device considered a two terminal: LED side pins shorted together and detector side pins shorted together.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур.	Max	Unit
Supply voltage	V _{AC}	-	-	120	Vac
Forward voltage	١ _F	15	20	25	mA
Peak current from snubber circuit	I _{SP}	-	-	1	А
Operating temperature	T _{opr}	-20		80	°C

Individual Electrical Characteristics (Ta = 25°C)

	Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
LED	Forward voltage	V _F	I _F =10mA	1.0	1.15	1.3	V
	Reverse current	I _R	V _R =5 V		—	10	μA
	Capacitance	CT	V=0, f=1MHz	-	30		pF
Detector	Peak off-state current	I _{DRM}	V _{DRM} =400V,Ta=110°C	_	—	100	μA
	Peak on-state voltage	V _{TM}	I _{TM} =1.5A	_	—	3.0	V
	Holding current	Ι _Η	R _L =100Ω	_	—	25	mA
	Critical rate of rise of off-state voltage	dv / dt	V _{in} =250V	200	500	_	V / µs
	Critical rate of rise of commutating voltage	dv / dt(c)	V _{in} =120Vrms, I _T =1.0A _{rms}		5		V / µs

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Trigger LED current	I _{FT}	V _T =6V	_	_	10	mA
Capacitance (input to output)	C _S	V _S =0, f=1MHz		1.5		pF
Isolation resistance	R _S	V _S =500V,R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	_	Ω
	BVS	AC, 1 minute	2500	_	_	Vrms
Isolation voltage		AC, 1 second, in oil	_	5000	_	VIIIS
		DC, 1 minute, in oil	_	5000	_	V _{dc}

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